

HAT2131R-EL-E

HAT2131R-EL-E Information

Mer.heisener.com	 HAT2131R-EL-E Renesas Electronics America Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single MOSFET N-CH 8SO 8-SOIC (0.154", 3.90mm Width) For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



HAT2131R-EL-E Specifications

Manufacturer Part Number	HAT2131R-EL-E
Manufacturer	Renesas Electronics America
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	8-SOIC (0.154", 3.90mm Width)
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	350V
Current - Continuous Drain (Id) @ 25°C	900mA (Ta)
Drive Voltage (Max Rds On, Min Rds On)	4V, 10V
Vgs(th) (Max) @ Id	-
Gate Charge (Qg) (Max) @ Vgs	20nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	460pF @ 25V
Vgs (Max)	$\pm 20 \mathrm{V}$
FET Feature	-
Power Dissipation (Max)	2.5W (Ta)
Rds On (Max) @ Id, Vgs	3 Ohm @ 450mA, 10V
Operating Temperature	150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	8-SOP
Package / Case	8-SOIC (0.154", 3.90mm Width)
	Report errors?

HAT2131R-EL-E Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

HAT2131R-EL-E Payment Methods



HAT2131R-EL-E Shipping Methods



If you have any question about HAT2131R-EL-E, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com